

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	464	(257/342).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/30 11:38
L2	114	11 and IGBT	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/30 12:01
L3	95	(257/121).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/30 12:06
L4	90	(257/124).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/30 12:21
L5	29	(257/125).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/30 12:02
L6	122	(257/168).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/30 12:25
L7	74	(257/172).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/30 12:22
L8	834	(257/E29.198).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/30 12:38
L9	2	09/873227	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/30 12:44
L10	5	shorted adj collector same IGBT	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/30 12:45
L11	0	("6798040").URPN	USPAT	OR	ON	2005/07/30 13:02
L12	798	(257/335).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/30 13:03

L13	98	112 and IGBT	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/30 14:06
S39	3	09/961361	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 13:19
S40	89	(IGBT MOSFET) and collector near3 short and (width thickness thick depth) with (drain collector)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 13:19
S41	842	IGBT and (freewheeling free adj wheel\$3) adj diode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 13:19
S42	923	(257/341).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/28 13:19
S43	330	S42 and IGBT	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 13:19
S44	834	(257/E29.198).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/28 13:19
S45	100	S44 and (width thickness depth) with collector	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 14:11
S46	12	S41 and 257/341.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 13:19
S47	26	S41 and (width thickness depth) with collector	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 13:19
S48	120	(IGBT MOSFET) and emitter adj short\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 13:19
S49	88	S45 not (S48 S46 S47)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 13:19

S50	120	(IGBT MOSFET) and emitter adj short\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 13:19
S51	131	(257/E29.22).CCLS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/28 13:19
S52	834	(257/E29.198).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/28 13:19
S53	71	S40 not (S45 S48 S46 S47)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 13:19
S54	140	S44 and (width thickness thick depth) with (anode collector)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 14:40
S55	40	S54 not S45	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 14:11
S56	53	S41 and (width thickness thick depth) with (anode collector)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 14:41
S57	24	S56 not (S47 S48 S46 S45 S54)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/28 14:48
S58	235	(257/152).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/28 14:49
S59	47	(257/143).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/07/28 14:49
S64	1	09/853661	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/30 11:38